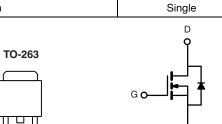


G D S Top View Vishay Siliconix

Automotive N-Channel 55 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	55				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.006				
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5 \text{ V}$	0.010				
I _D (A)	110				
Configuration	Single				



N-Channel MOSFET

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Package with Low Thermal Resistance
- AEC-Q101 Qualified^c
- 100 % Rq and UIS Tested
- Compliant to RoHS Directive 2002/95/EC



FREE

ORDERING INFORMATION	
Package	TO-263
Lead (Pb)-free and Halogen-free	SQM110N05-06L-GE3

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage		V_{DS}	55	V		
Gate-Source Voltage		V_{GS}	GS ± 20			
Continuous Drain Current	T _C = 25 °C	1	110			
Continuous Drain Current	T _C = 125 °C	l _D	64			
Continuous Source Current (Diode Conduct	I _S	120	Α			
Pulsed Drain Current ^a	I _{DM}	443				
Single Pulse Avalanche Current	1 0411	I _{AS}	61			
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	186	mJ		
Maximum Davier Dissinations	T _C = 25 °C	р	157	14/		
Maximum Power Dissipation ^a	T _C = 125 °C	P_{D}	52	W		
Operating Junction and Storage Temperatur	T _J , T _{stg}	- 55 to + 175	°C			

THERMAL RESISTANCE RATINGS							
PARAMETER		SYMBOL	LIMIT	UNIT			
Junction-to-Ambient PC	CB Mount ^b	R _{thJA}	40	°C/W			
Junction-to-Case (Drain)		R _{thJC}	0.95	C/VV			

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. When mounted on 1" square PCB (FR-4 material).
- c. Parametric verification ongoing.



Vishay Siliconix

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static							,	
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0, I _D = 250 μA		55	-	-	V	
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	1.5	2.0	2.5	v	
Gate-Source Leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-		± 100	nA	
		V _{GS} = 0 V	V _{DS} = 55 V	-	-	1.0		
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = 55 V, T _J = 125 °C	-	-	50	μΑ	
		V _{GS} = 0 V	V _{DS} = 55 V, T _J = 175 °C	-		150	1	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	120	-	-	Α	
		V _{GS} = 10 V	I _D = 30 A	-	0.0047	0.006	Ω	
Drain Cauras On State Besistance	В	V _{GS} = 10 V	I _D = 30 A, T _J = 125 °C	-	-	0.0105		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A, T _J = 175 °C	-	-	0.0132		
		V _{GS} = 4.5 V	I _D = 20 A	-	0.008	0.010		
Forward Transconductanceb	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	90	-	S	
Dynamic ^b								
Input Capacitance	C _{iss}				3550	4440		
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$	-	610	765	pF	
Reverse Transfer Capacitance	C _{rss}			-	288	360		
Total Gate Charge ^c	Qg			-	73	110	nC	
Gate-Source Charge ^c	Q_{gs}	V _{GS} = 10 V	$V_{DS} = 28 \text{ V}, I_{D} = 110 \text{ A}$	-	14.5	-		
Gate-Drain Charge ^c	Q_{gd}			-	16.8	-		
Gate Resistance	Rg	f = 1 MHz		0.62	1.2	1.85	Ω	
Turn-On Delay Time ^c	t _{d(on)}			-	12	18		
Rise Time ^c	t _r	$V_{DD} = 28 \text{ V}, \text{ R}_{L} = 0.25 \Omega$ $I_{D} \cong 110 \text{ A}, \text{ V}_{GEN} = 10 \text{ V}, \text{ R}_{g} = 2.5 \Omega$		-	13	20	ns	
Turn-Off Delay Time ^c	t _{d(off)}			-	37	56		
Fall Time ^c	t _f			-	13	20		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	443	Α	
Forward Voltage	V_{SD}	I _F = 85 A, V _{GS} = 0		-	0.9	1.5	V	

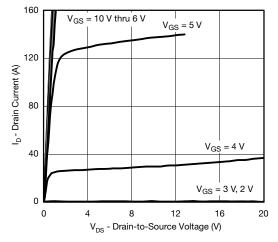
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

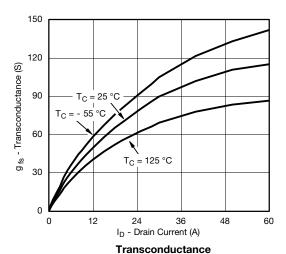
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

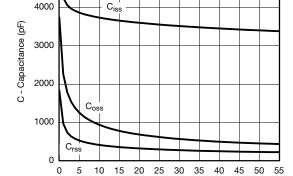


TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Output Characteristics

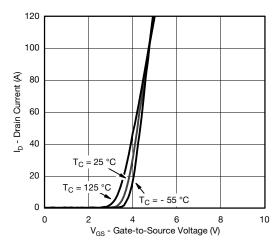




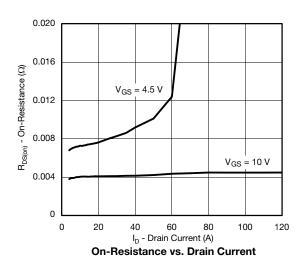
5000

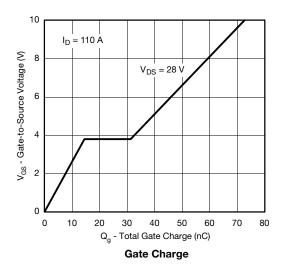
V_{DS} - Drain-to-Source Voltage (V)

Capacitance



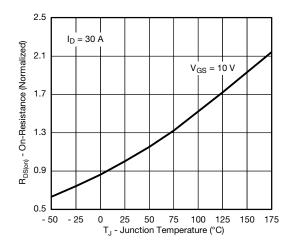
Transfer Characteristics



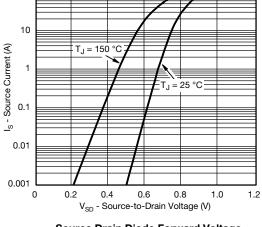




TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

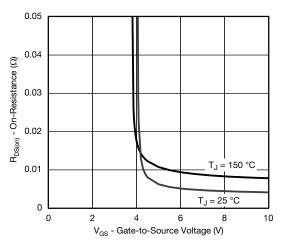


On-Resistance vs. Junction Temperature

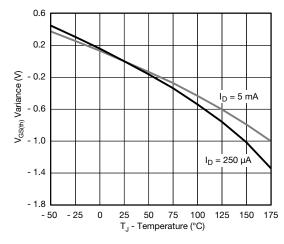


100

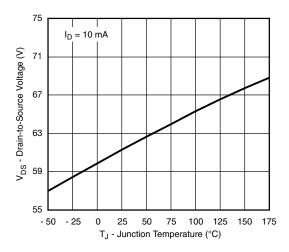
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



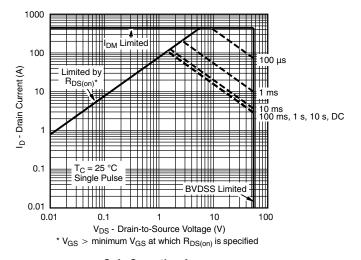
Threshold Voltage



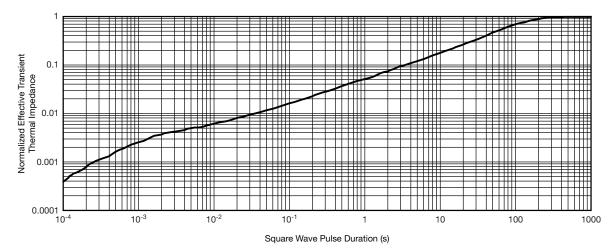
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



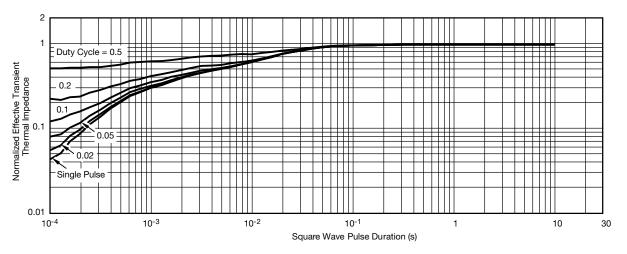
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68838.



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



⋝:	,	 	b— b1–		ļ	ļ
2:	П				5	ပ
	SE	СТ	ION	ΙΔ.	- 1 - Δ	Ŧ

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

	INCHES		HES	MILLIMETERS		
	DIM.	MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
D3		0.045	0.055	1.143	1.397	
D4		0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100	BSC	2.54 BSC		
	K	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4 0.010		BSC	0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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